

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSVI)

TPC8123

Lithium Ion Battery Applications

Power Management Switch Applications

Unit: mm

- Small footprint due to small and thin package
- Low drain-source ON-resistance: $R_{DS(ON)} = 7.0 \text{ m}\Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 36 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = -10 \text{ }\mu\text{A}$ (max) ($V_{DS} = -30 \text{ V}$)
- Enhancement mode: $V_{th} = -0.8 \text{ to } -2.0 \text{ V}$ ($V_{DS} = -10 \text{ V}$, $I_D = -0.5 \text{ mA}$)

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

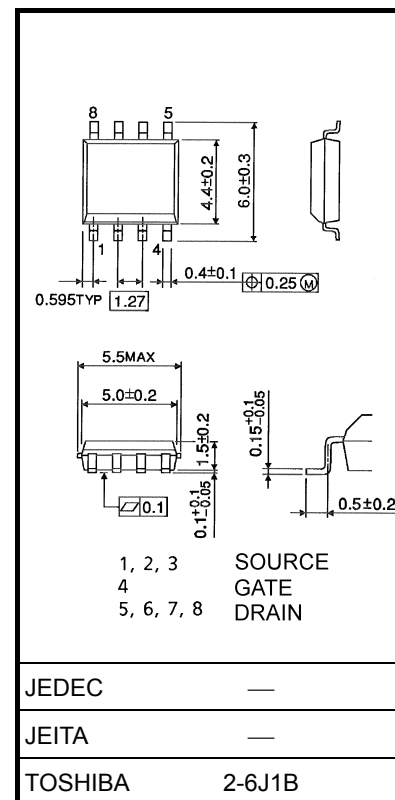
Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	-30	V
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V_{DGR}	-30	V
Gate-source voltage		V_{GSS}	-25/+20	V
Drain current	DC (Note 1)	I_D	-11	A
	Pulse (Note 1)	I_{DP}	-44	
Drain power dissipation ($t = 10 \text{ s}$) (Note 2a)		P_D	1.9	W
Drain power dissipation ($t = 10 \text{ s}$) (Note 2b)		P_D	1.0	W
Single pulse avalanche energy (Note 3)		E_{AS}	79	mJ
Avalanche current (Note 1)		I_{AR}	-11	A
Repetitive avalanche energy (Note 2a) (Note 4)		E_{AR}	0.04	mJ
Channel temperature		T_{ch}	150	$^\circ\text{C}$
Storage temperature range		T_{stg}	-55 to 150	$^\circ\text{C}$

Note 1, Note 2, Note 3 and Note 4: See the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

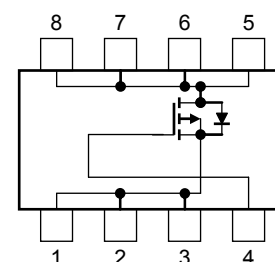
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.080 g (typ.)

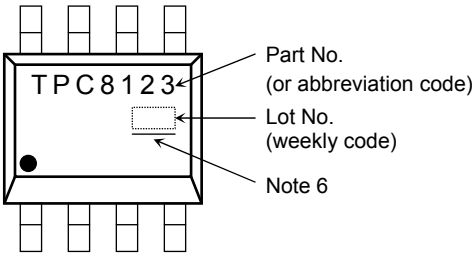
Circuit Configuration



Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R _{th} (ch-a)	65.8	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th} (ch-a)	125	°C/W

Marking (Note 5)

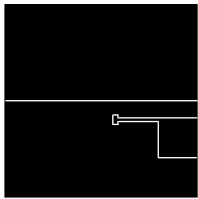


Note 6: A line under a Lot No. identifies the indication of product Labels
[[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

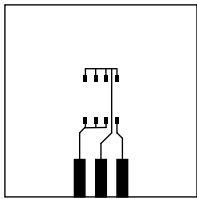
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



(a)



(b)

Note 3: V_{DD} = -24 V, T_{ch} = 25 °C (initial), L = 500 μH, R_G = 25 Ω, I_{AR} = -11 A

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

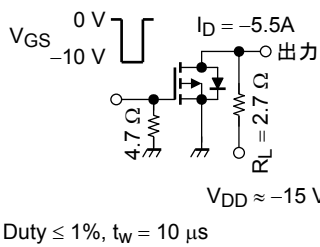
Note 5: • on lower left of the marking indicates Pin 1.

※ Weekly code: (Three digits)



Week of manufacture
(01 for the first week of a year: sequential number up to 52 or 53)
Year of manufacture
(The last digit of a year)

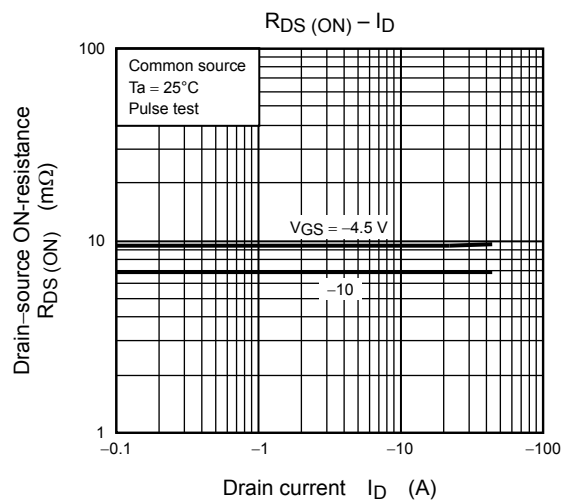
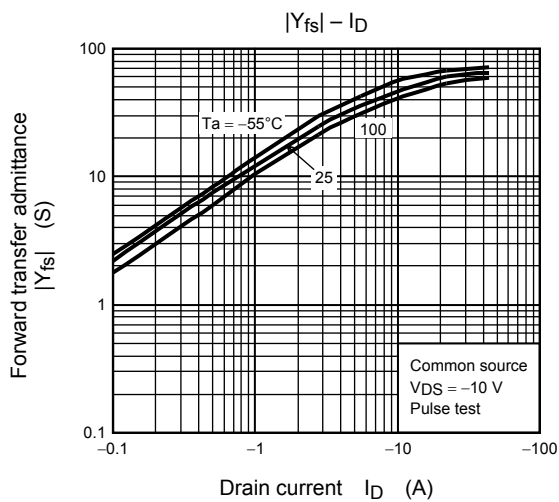
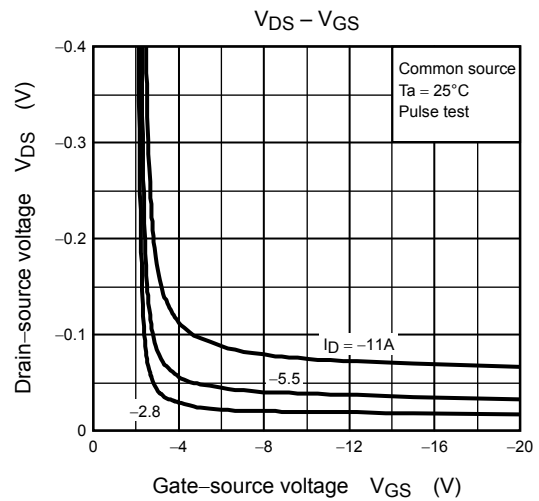
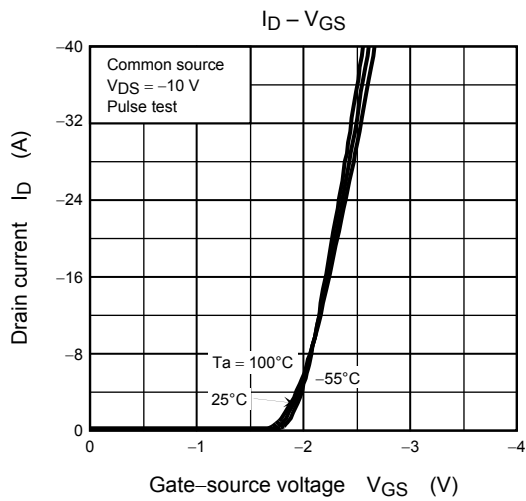
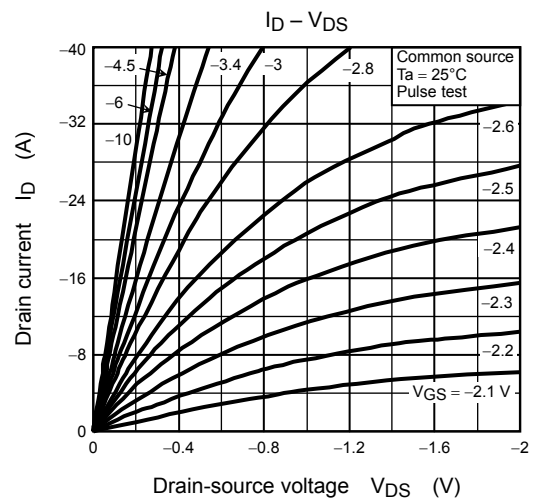
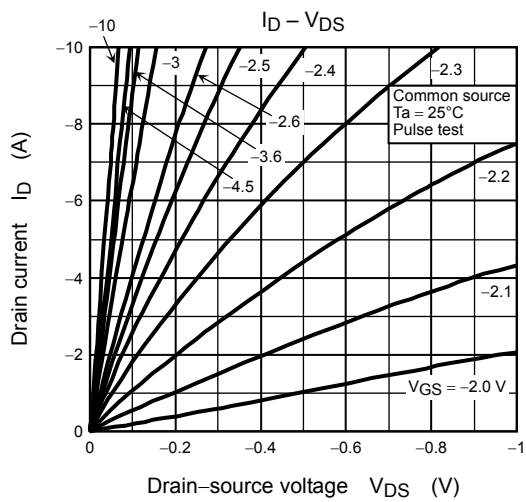
Electrical Characteristics (Ta = 25°C)

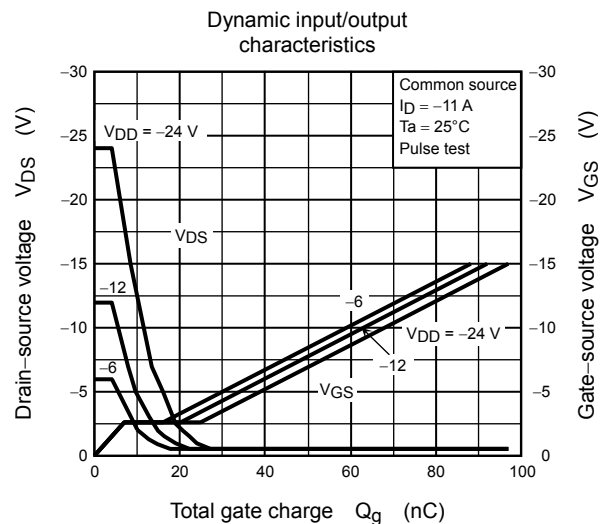
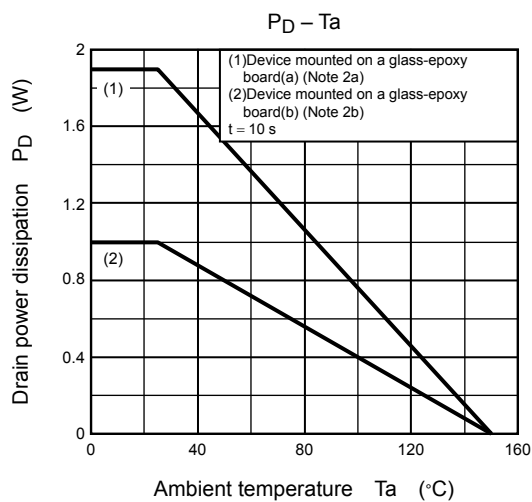
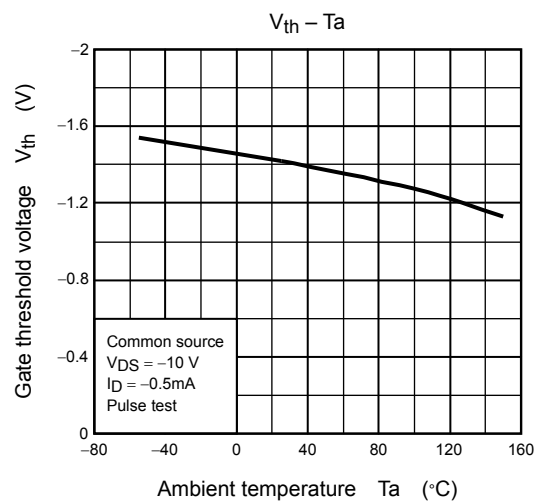
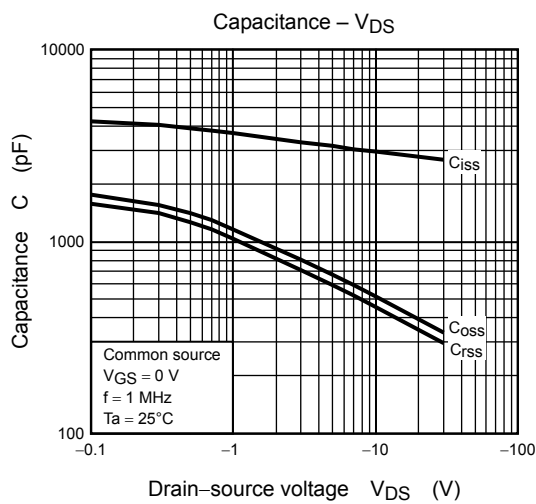
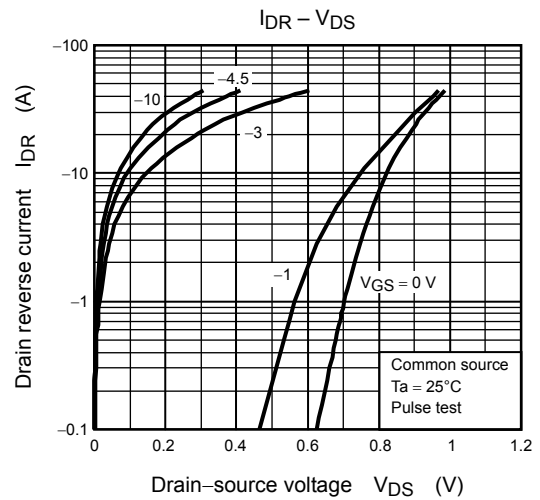
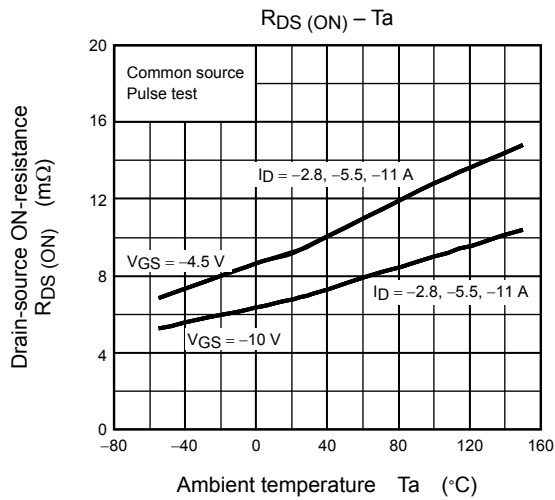
Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I _{GSS}	V _{GS} = ±20 V, V _{DS} = 0 V	—	—	±100	nA
Drain cut-OFF current		I _{DSS}	V _{DS} = -30 V, V _{GS} = 0 V	—	—	-10	μA
Drain-source breakdown voltage		V _(BR) DSS	I _D = -10 mA, V _{GS} = 0 V	-30	—	—	V
		V _(BR) DSX	I _D = -10 mA, V _{GS} = 10 V (Note 7)	-21	—	—	
Gate threshold voltage		V _{th}	V _{DS} = -10 V, I _D = -0.5 mA	-0.8	—	-2.0	V
Drain-source ON-resistance		R _{DS} (ON)	V _{GS} = -4.5 V, I _D = -5.5 A	—	9.5	12.5	mΩ
			V _{GS} = -10 V, I _D = -5.5 A	—	7.0	9.0	
Forward transfer admittance		Y _{fs}	V _{DS} = -10 V, I _D = -5.5 A	18	36	—	S
Input capacitance		C _{iss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	—	2940	—	pF
Reverse transfer capacitance		C _{rss}		—	460	—	
Output capacitance		C _{oss}		—	520	—	
Switching time	Rise time	t _r		—	10	—	ns
	Turn-ON time	t _{on}		—	18	—	
	Fall time	t _f		—	80	—	
	Turn-OFF time	t _{off}		—	250	—	
Total gate charge (gate-source plus gate-drain)		Q _g	V _{DD} ≈ -24 V, V _{GS} = -10 V, I _D = -11 A	—	68	—	nC
Gate-source charge 1		Q _{gs1}		—	7	—	
Gate-drain (“miller”) charge		Q _{gd}		—	18	—	

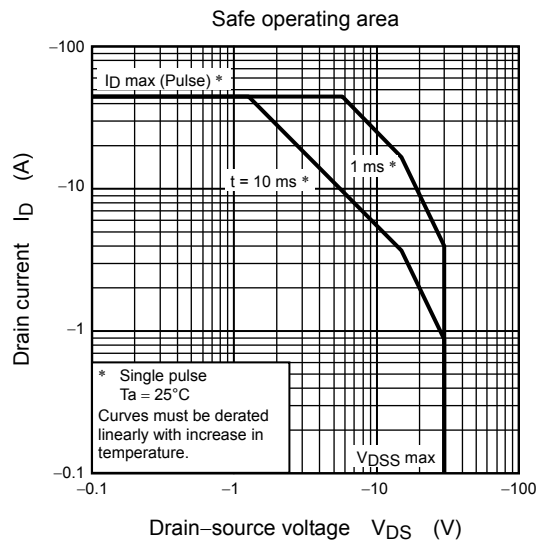
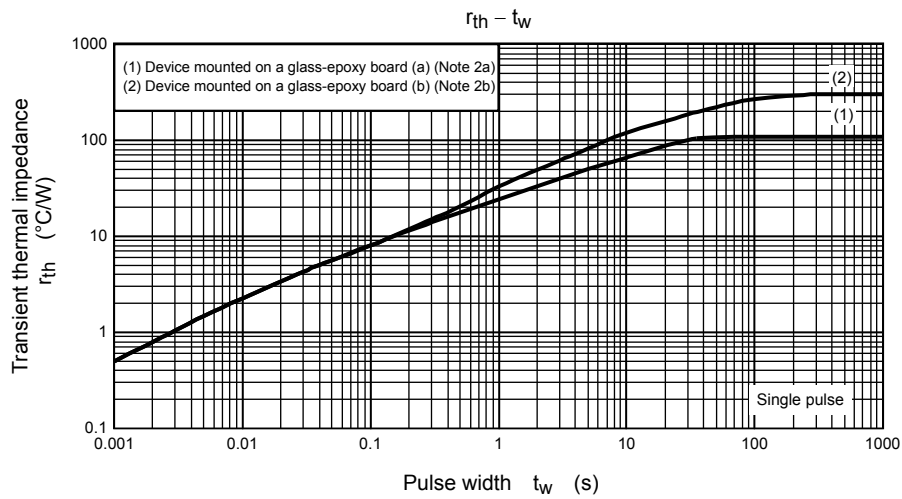
Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Drain reverse current	Pulse (Note 1)	I_{DRP}	—	—	—	-44	A
Forward voltage (diode)		V_{DSF}	$I_{DR} = -11 \text{ A}, V_{GS} = 0 \text{ V}$	—	—	1.2	V

Note 7: VDSX mode (the application of a plus voltage between gate and source) may cause decrease in maximum rating of drain-source voltage.







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